
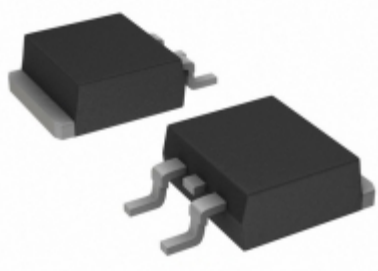

	<h2 style="color: red;">FQB6N60CTM</h2>
	<p>Hersteller-Teilenummer: FQB6N60CTM</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 5.5A D2PAK</p> <p>Datenblätter:  FQB6N60CTM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4940 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB6N60CTM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 600V 5.5A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	4940 pcs Stock
detaillierte Beschreibung	N-Channel 600V 5.5A (Tc) 125W (Tc) Surface Mount
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.5A (Tc)
Rds On (Max) @ Id, Vgs	2 Ohm @ 2.75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	810pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)














































FQB6N60CTM ist neu im Original, Suche FQB6N60CTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB6N60CTM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB6N60CTM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB6N60 FSC FQB6N60 FSC</p>	 <p>FQB6N60C Fairchild/ON Semiconductor FQB6N60C FAIRCHILD</p>	 <p>FQB6N70TM Fairchild/ON Semiconductor MOSFET N-CH 700V 6.2A D2PAK</p>	 <p>FQB6N50TM Fairchild/ON Semiconductor MOSFET N-CH 500V 5.5A D2PAK</p>
 <p>FQB6N60TM Fairchild/ON Semiconductor MOSFET N-CH 600V 6.2A D2PAK</p>	 <p>FQB6N50 Fairchild/ON Semiconductor FQB6N50 FAIRCHILD</p>	 <p>FQB6N60TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 6.2A D2PAK</p>	 <p>FQB6N70 FSC FQB6N70 FSC</p>

heiße Teile

Mehr

 FQB5N30TM	 FQB5N30TM	 FQB5N50C	 FQB5N50CF	 FQB5N50CTM
 FQB5N50CTM	 FQB5N60CTM	 FQB5N60CTM	 FQB5N90TM	 FQB5N90TM
 FQB5P10TM	 FQB5P10TM	 FQB630TM	 FQB630TM	 FQB65N06
 FQB65N06TM	 FQB65N06TM	 FQB6N40C	 FQB6N40CF	 FQB6N40CTM
 FQB6N40CTM	 FQB6N50TM	 FQB6N50TM	 FQB6N60C	 FQB6N60CTM
 FQB6N60TM	 FQB6N60TM	 FQB6N70TM	 FQB6N70TM	 FQB6N90TM
 FQB6N90TM_AM002	 FQB6N90TM_AM002	 FQB7042FB	 FQB7045FB	 FQB70N03
 FQB70N06	 FQB70N08	 FQB70N10TM	 FQB7N10L	 FQB7N20L
 FQB7N60TM	 FQB7N60TM	 FQB7N65C	 FQB7N65CTM	 FQB7N65CTM
 FQB7P20TM	 FQB7P20TM	 FQB85N06	 FQB85N06TM	 FQB8N25TM

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